2SK1838(L), 2SK1838(S)

Silicon N-Channel MOS FET

HITACHI

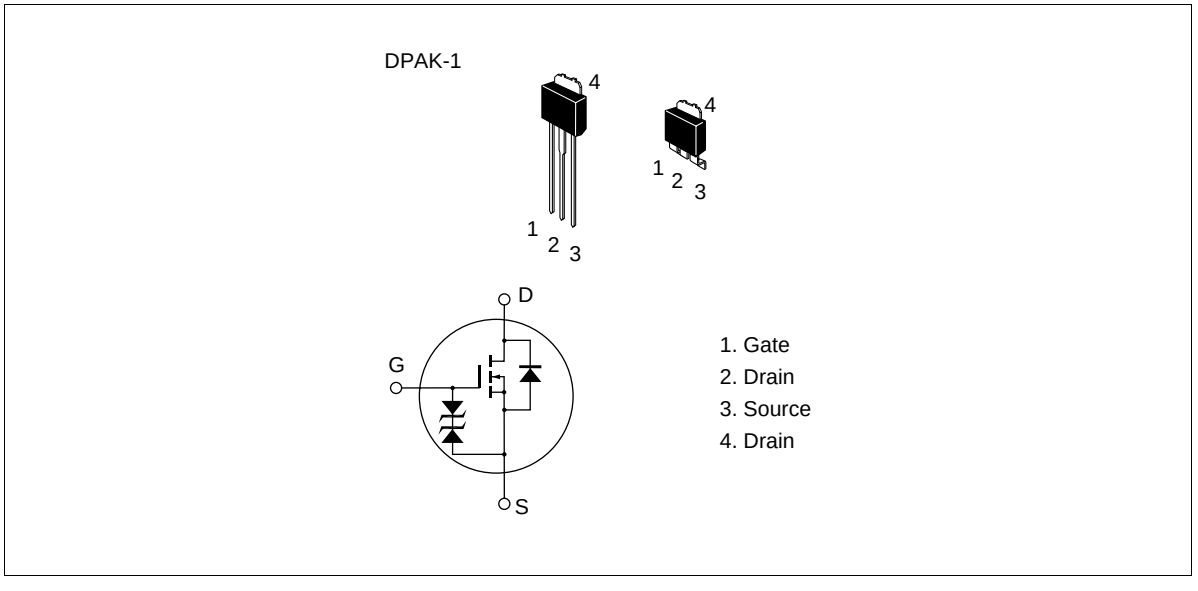
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switchingregulator, DC-DC converter

Outline



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Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	250	V
Gate to source voltage	V_{GSS}	±30	V
Drain current	I_D	1	A
Drain peak current	$I_{D(pulse)}$*[1]	2	A
Body to drain diode reverse drain current	I_{DR}	1	A
Channel dissipation	Pch*[2]	10	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	–55 to +150	°C

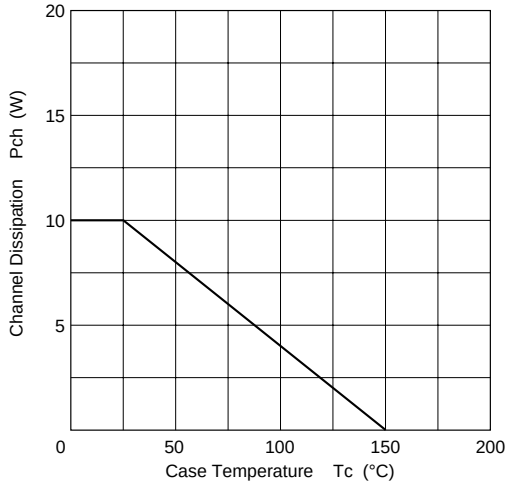
Notes 1. PW ≤ 10 µs, duty cycle ≤ 1 %
2. Value at Tc = 25 °C

Electrical Characteristics (Ta = 25°C)

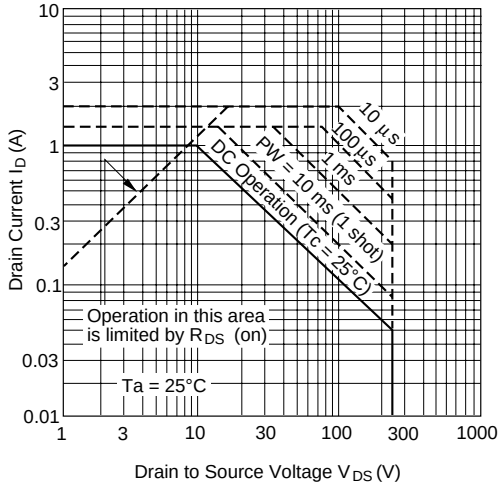
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	250	—	—	V	I_D = 10 mA, V_{GS} = 0
Gate to source breakdown voltage	$V_{(BR)GSS}$	±30	—	—	V	I_G = ±100 µA, V_{DS} = 0
Gate to source leak current	I_{GSS}	—	—	±10	µA	V_{GS} = ±25 V, V_{DS} = 0
Zero gate voltage drain current	I_{DSS}	—	—	100	µA	V_{DS} = 200 V, V_{GS} = 0
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	—	3.0	V	V_{DS} = 10 V, I_D = 1 mA
Forward transfer admittance	$\|y_{fs}\|$	0.3	0.5	—	S	V_{DS} = 10 V, I_D = 0.5 A *[1]
Static drain to source on state resistance	$R_{DS(on)}$	—	5.5	8.0	Ω	I_D = 0.5 A, V_{GS} = 10 V *[1]
Input capacitance	Ciss	—	60	—	pF	V_{DS} = 10 V, V_{GS} = 0,
Output capacitance	Coss	—	30	—	pF	f = 1 MHz
Reverse transfer capacitance	Crss	—	5	—	pF	
Turn-on delay time	$t_{d(on)}$	—	5	—	ns	V_{GS} = 10 V, I_D = 0.5 A,
Rise time	t_r	—	6	—	ns	R_L = 60 Ω
Turn-off delay time	$t_{d(off)}$	—	10	—	ns	
Fall time	t_f	—	4.5	—	ns	
Body to drain diode forward voltage	V_{DF}	—	0.96	—	V	I_F = 1 A, V_{GS} = 0
Body to drain diode reverse recovery time	t_{rr}	—	160	—	ns	I_F = 7 A, V_{GS} = 0, di_F/dt = 100 A/µs

Note 1. Pulse test

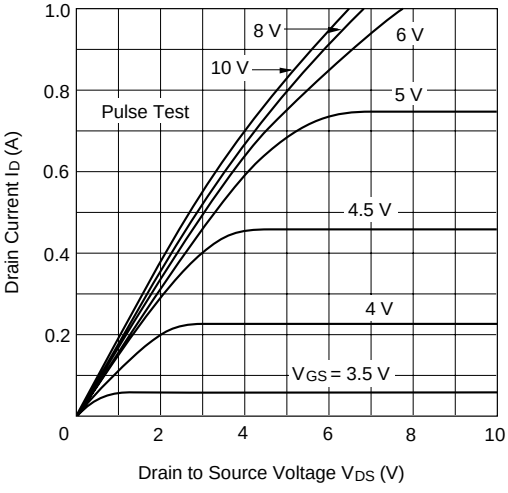
Power vs. Temperature Derating



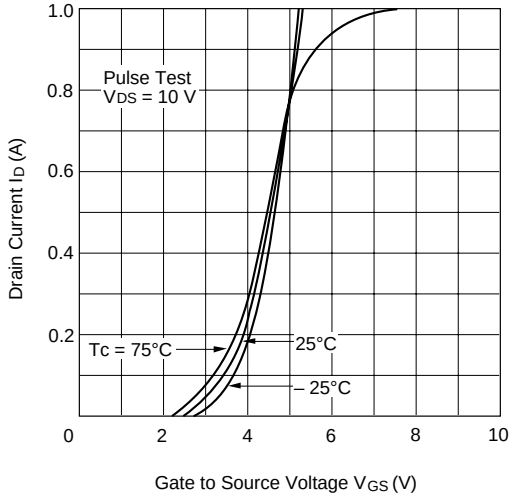
Maximum Safe Operation Area



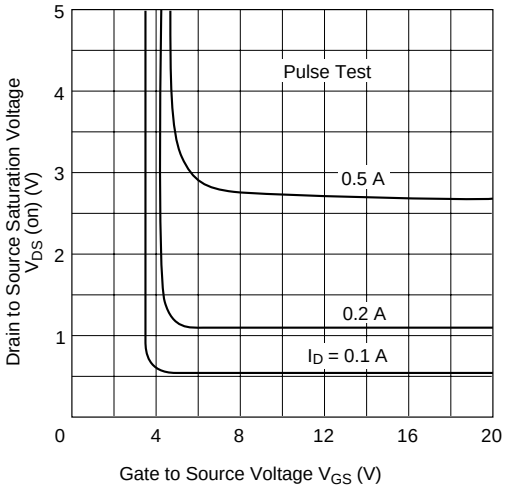
Typical Output Characteristics



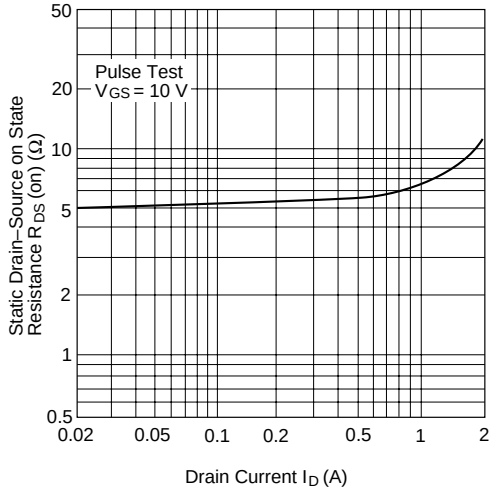
Typical Transfer Characteristics



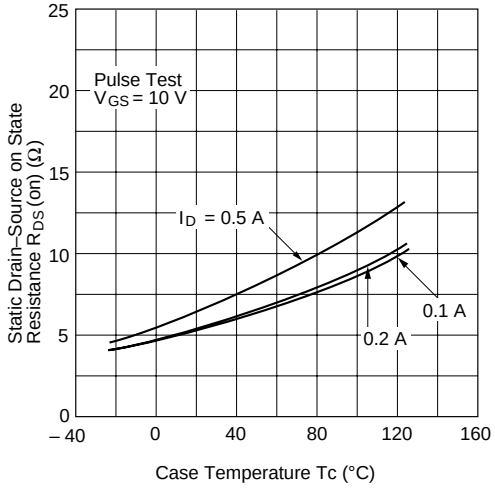
Drain to Source Saturation Voltage vs. Gate to Source Voltage



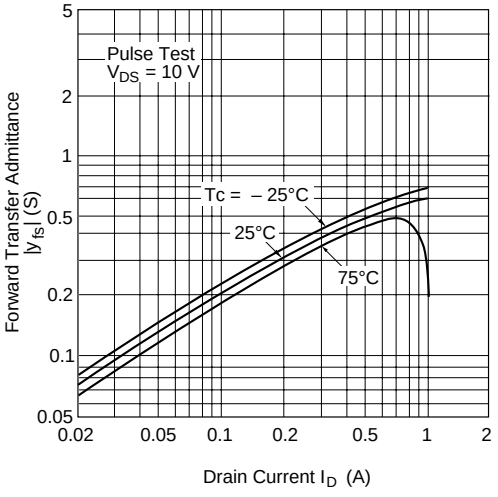
Static Drain to Source on State Resistance vs. Drain Current



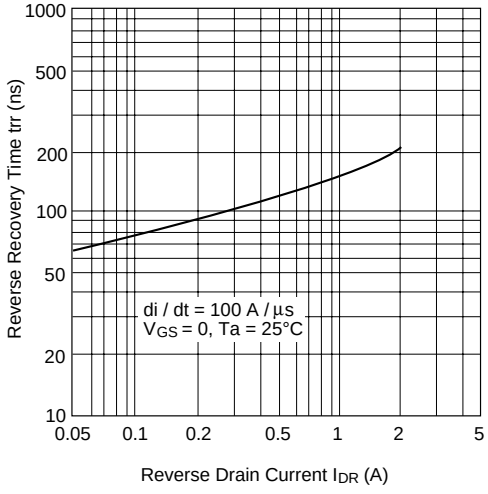
Static Drain to Source on State Resistance vs. Temperaure



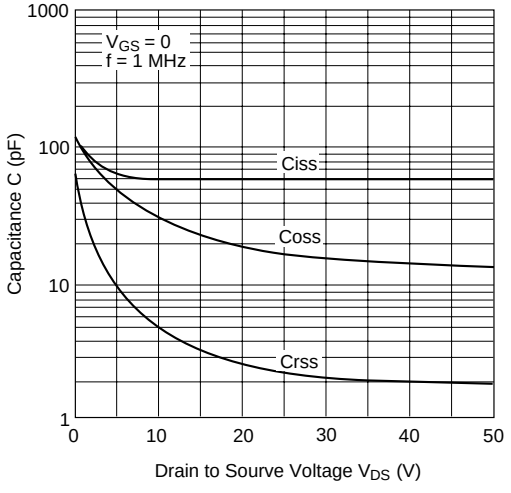
Forward Transfer Admittance vs. Drain Current



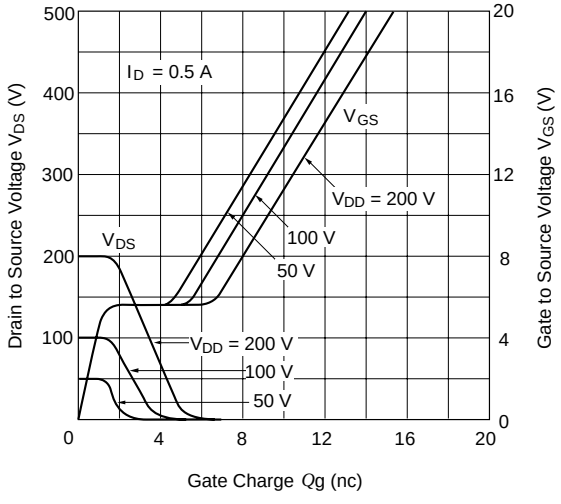
Body to Drain Diode Reverse Recovery Time



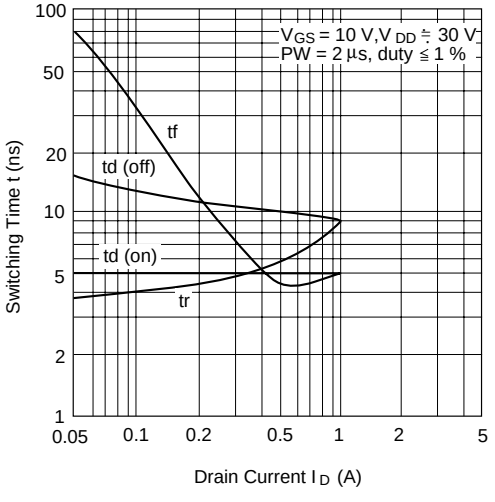
Typical Capacitance vs. Drain to Sorce Voltage



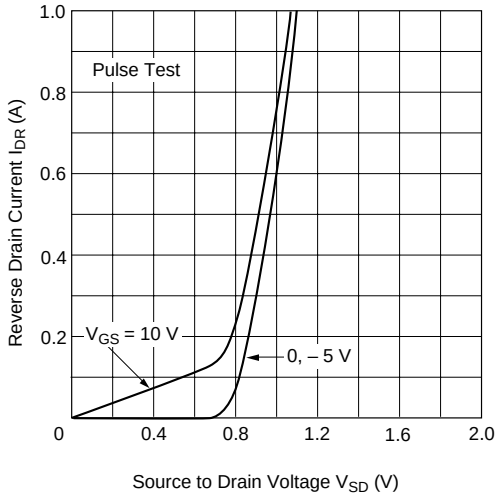
Dynamic Input Characteristics



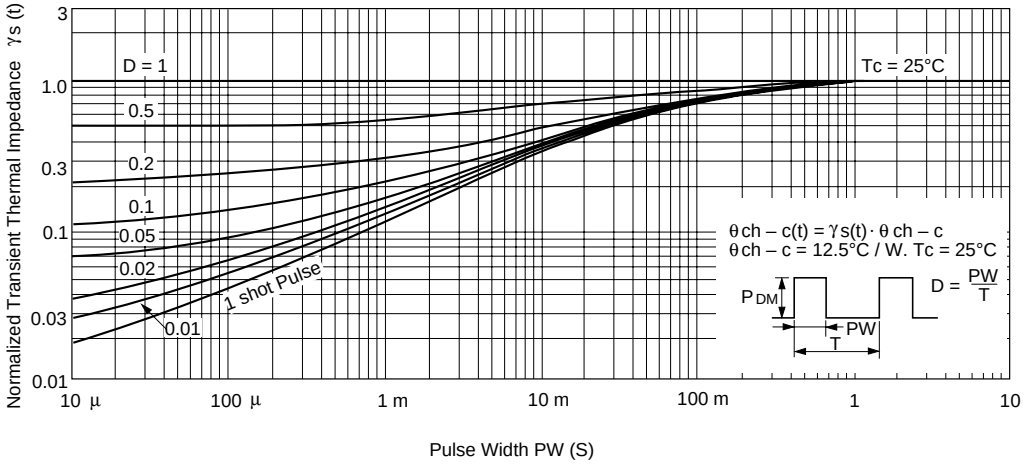
Switching Characteristics

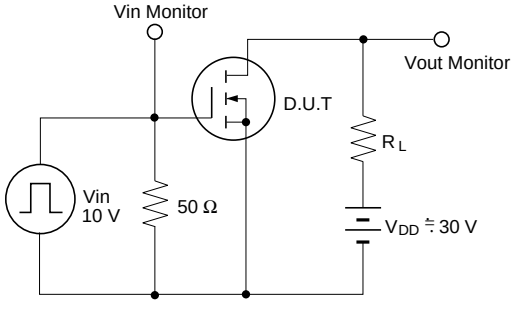


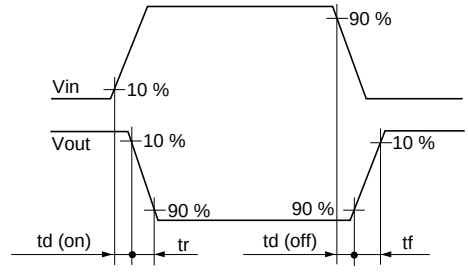
Reverse Drain Current
vs. Source to Drain Voltage



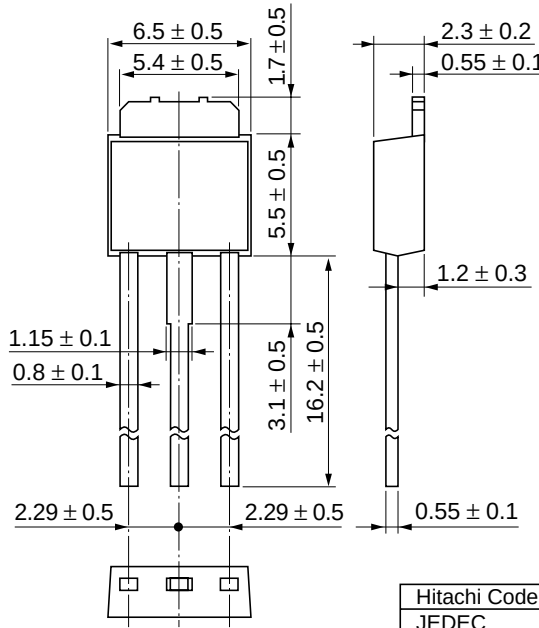
Normalized Transient Thermal Impedance vs. Pulse Width

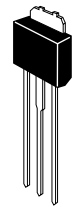






Unit: mm





Hitachi Code	DPAK (L)-(1)
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.42 g

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